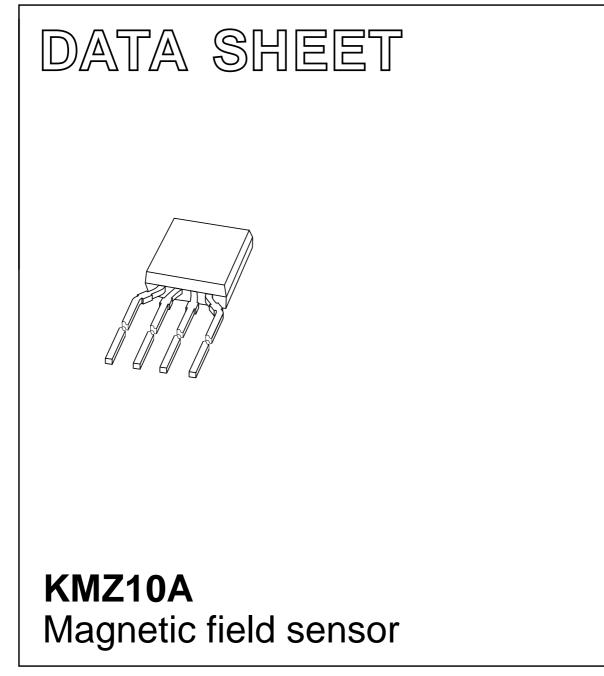
## DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 1996 Nov 08 File under Discrete Semiconductors, SC17 1998 Mar 24

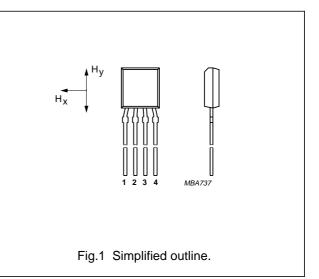


#### DESCRIPTION

The KMZ10A is an extremely sensitive magnetic field sensor, employing the magnetoresistive effect of thin-film permalloy. Its properties enable this sensor to be used in a wide range of applications for navigation, current and field measurement, revolution counters, angular or linear position measurement and proximity detectors, etc.

#### PINNING

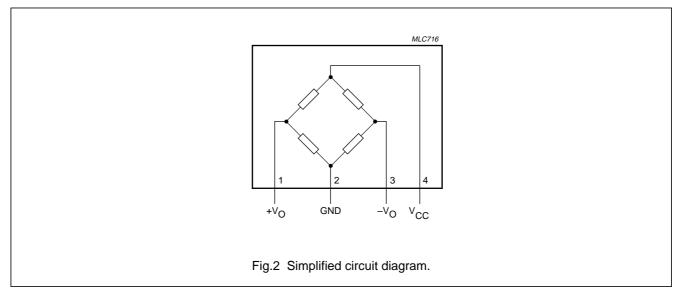
PIN	SYMBOL	DESCRIPTION		
1	+V <sub>O</sub>	output voltage		
2	GND	ground		
3	-V <sub>O</sub>	output voltage		
4	V <sub>CC</sub>	supply voltage		



#### QUICK REFERENCE DATA

SYMBOL	PARAMETER	MIN.	TYP.	MAX.	UNIT
V <sub>CC</sub>	bridge supply voltage	-	5	-	V
T <sub>bridge</sub>	bridge operating temperature	-40	_	+150	°C
H <sub>y</sub>	magnetic field strength	-0.5	_	+0.5	kA/m
H <sub>x</sub>	auxiliary field	-	0.5	-	kA/m
S	sensitivity	-	16	-	$\frac{mV/V}{kA/m}$
R <sub>bridge</sub>	bridge resistance	0.8	-	1.6	kΩ
V <sub>offset</sub>	offset voltage	-1.5	_	+1.5	mV/V

#### **CIRCUIT DIAGRAM**



### KMZ10A

## KMZ10A

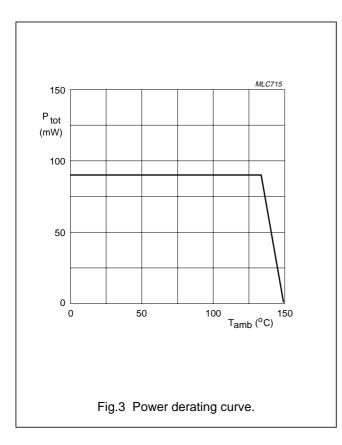
#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CC</sub>	bridge supply voltage		_	9	V
P <sub>tot</sub>	total power dissipation	up to T <sub>amb</sub> = 134 °C	_	90	mW
T <sub>stg</sub>	storage temperature	note 1	-65	+150	°C
T <sub>bridge</sub>	bridge operating temperature		-40	+150	°C

#### Note

1. Maximum operating temperature of the thin-film permalloy.



## KMZ10A

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT	
R <sub>th j-a</sub>	thermal resistance from junction to ambient	180	K/W	

#### CHARACTERISTICS

 $T_{amb}$  = 25 °C;  $H_x$  = 0.5 kA/m; notes 1 and 2;  $V_{CC}$  = 5 V unless otherwise specified.

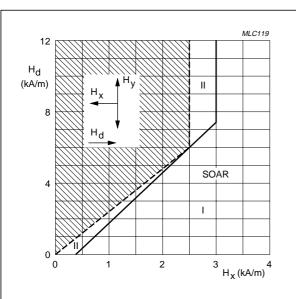
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Hy	magnetic field strength	note 2	-0.5	_	+0.5	kA/m
S	sensitivity	notes 2 and 3	13	-	19	$\frac{mV/V}{kA/m}$
TCVO	temperature coefficient of output voltage	V <sub>CC</sub> = 5 V; T <sub>amb</sub> = -25 to +125 °C	-	-0.4	-	%/K
		$I_{CC} = 3 \text{ mA};$ $T_{amb} = -25 \text{ to } +125 ^{\circ}\text{C}$	-	-0.15	-	%/K
R <sub>bridge</sub>	bridge resistance		0.8	-	1.6	kΩ
TCR <sub>bridge</sub>	temperature coefficient of bridge resistance	T <sub>bridge</sub> = -25 to +125 °C	-	0.25	-	%/K
Voffset	offset voltage		-1.5	-	+1.5	mV/V
TCV <sub>offset</sub>	offset voltage drift	T <sub>bridge</sub> = −25 to +125 °C	-6	-	+6	$\frac{\mu V/V}{K}$
FL	linearity deviation of output	H <sub>y</sub> = 0 to ±0.25 kA/m	-	-	0.8	%·FS
	voltage	$H_y = 0$ to $\pm 0.4$ kA/m	_	_	2.5	%·FS
		$H_y = 0$ to ±0.5 kA/m	-	-	4.0	%·FS
FH	hysteresis of output voltage		-	-	0.5	%·FS
f	operating frequency		0	_	1	MHz

#### Notes

- 1. Before first operation or after operation outside the SOAR (Fig.4) the sensor has to be reset by application of an auxiliary field  $H_x = 3 \text{ kA/m}$ .
- 2. No disturbing field (H<sub>d</sub>) allowed; for stable operation under disturbing conditions see Fig.4 (SOAR) and see Fig.5 for decrease of sensitivity.

3. 
$$S = \frac{(V_0 \text{ at } H_y = 0.4 \text{ kA/m}) - (V_0 \text{ at } H_y = 0)}{0.4 \times V_{CC}}$$

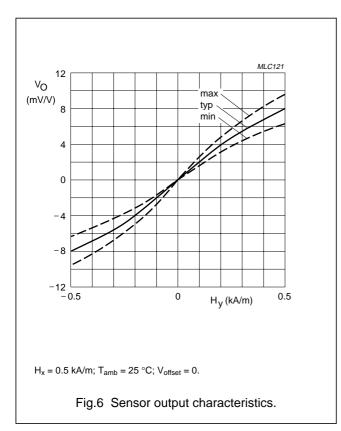
## KMZ10A

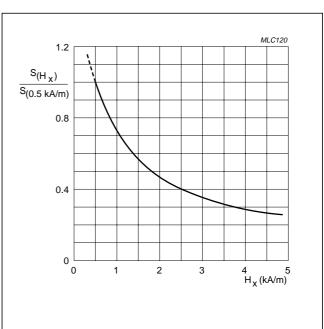


In applications with H<sub>x</sub> < 3 kA/m, the sensor has to be reset, after leaving the SOAR, by an auxiliary field of H<sub>x</sub> = 3 kA/m. I = Region of permissible operation.

II = Permissible extension if  $H_y < 0.15$  A/m.

Fig.4 Safe Operating Area (permissible disturbing field H<sub>d</sub> as a component of auxiliary field H<sub>x</sub>).



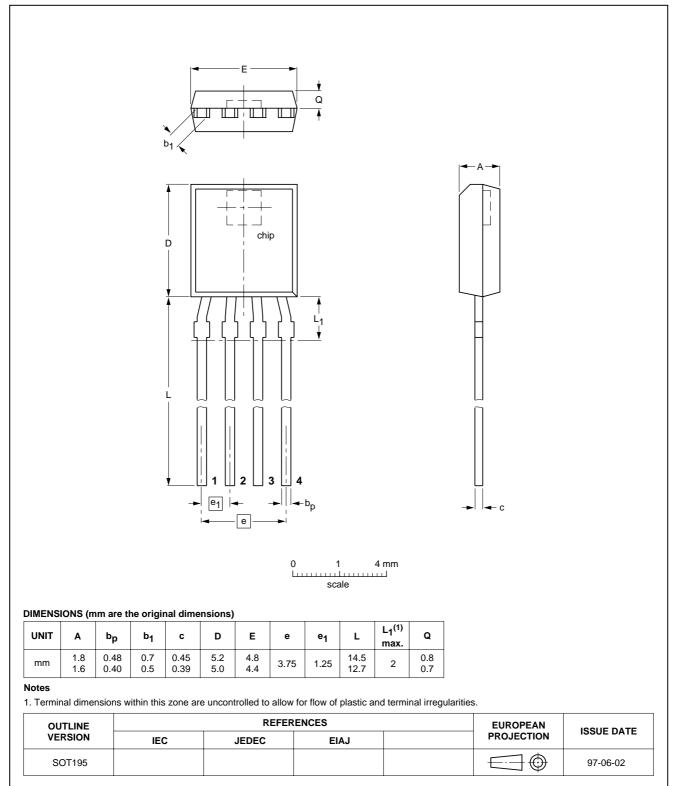


In applications with H\_x  $\leq$  3 kA/m, the sensor has to be reset by an auxiliary field of H\_x = 3 kA/m before using.

Fig.5 Relative sensitivity (ratio of sensitivity at certain  $H_x$  and sensitivity at  $H_x = 0.5$  kA/m).

#### PACKAGE OUTLINE

#### Plastic single-ended flat package; 4 in-line leads



### KMZ10A

SOT195

Product specification

## KMZ10A

#### DEFINITIONS

Data Sheet Status			
Objective specification	n This data sheet contains target or goal specifications for product development.		
Preliminary specification This data sheet contains preliminary data; supplementary data may be published late			
Product specification This data sheet contains final product specifications.			
Limiting values			
more of the limiting values may of the device at these or at an	ccordance with the Absolute Maximum Rating System (IEC 134). Stress above one or ay cause permanent damage to the device. These are stress ratings only and operation by other conditions above those given in the Characteristics sections of the specification niting values for extended periods may affect device reliability.		
Application information			

Where application information is given, it is advisory and does not form part of the specification.

#### LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

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